

# 74AUP3G14

## Low-power triple Schmitt trigger inverter

Rev. 1 — 22 December 2015

Product data sheet

### 1. General description

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The 74AUP3G14 provides three inverting buffers with Schmitt trigger action which accept standard input signals. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage  $V_{T+}$  and the negative voltage  $V_{T-}$  is defined as the input hysteresis voltage  $V_H$ .

### 2. Features and benefits

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- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot  $< 10\%$  of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$

### 3. Applications

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- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator



## 4. Ordering information

**Table 1.** Ordering information

| Type number | Package           |        |                                                                                             |          |
|-------------|-------------------|--------|---------------------------------------------------------------------------------------------|----------|
|             | Temperature range | Name   | Description                                                                                 | Version  |
| 74AUP3G14DC | –40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm                  | SOT765-1 |
| 74AUP3G14GT | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | SOT833-1 |
| 74AUP3G14GF | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm         | SOT1089  |
| 74AUP3G14GD | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm    | SOT996-2 |
| 74AUP3G14GM | –40 °C to +125 °C | XQFN8  | plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm   | SOT902-2 |
| 74AUP3G14GN | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm       | SOT1116  |
| 74AUP3G14GS | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm      | SOT1203  |

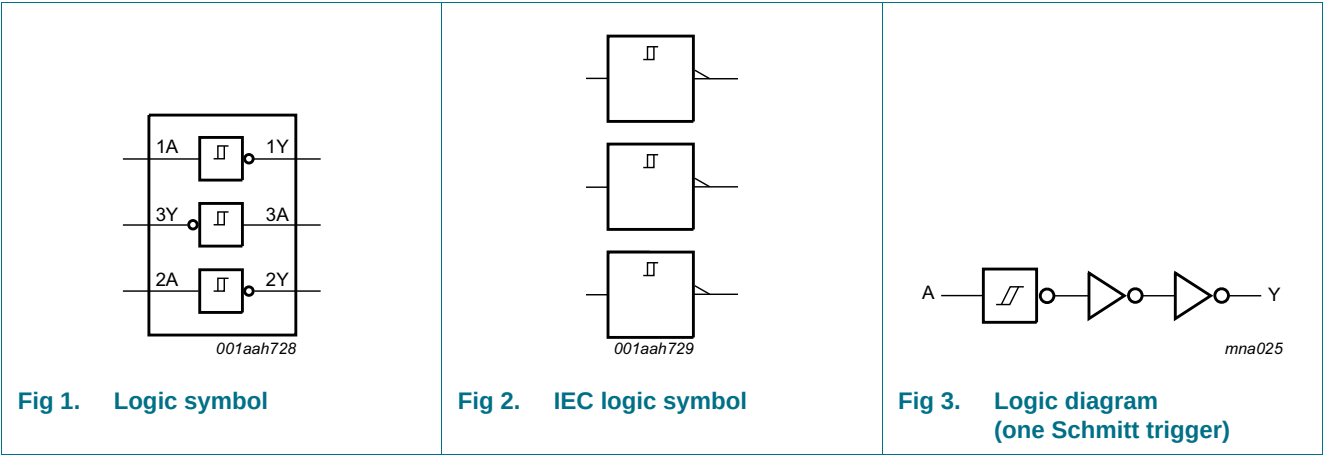
## 5. Marking

**Table 2.** Marking

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 74AUP3G14DC | pK                          |
| 74AUP3G14GT | pK                          |
| 74AUP3G14GF | pK                          |
| 74AUP3G14GD | pK                          |
| 74AUP3G14GM | pK                          |
| 74AUP3G14GN | pK                          |
| 74AUP3G14GS | pK                          |

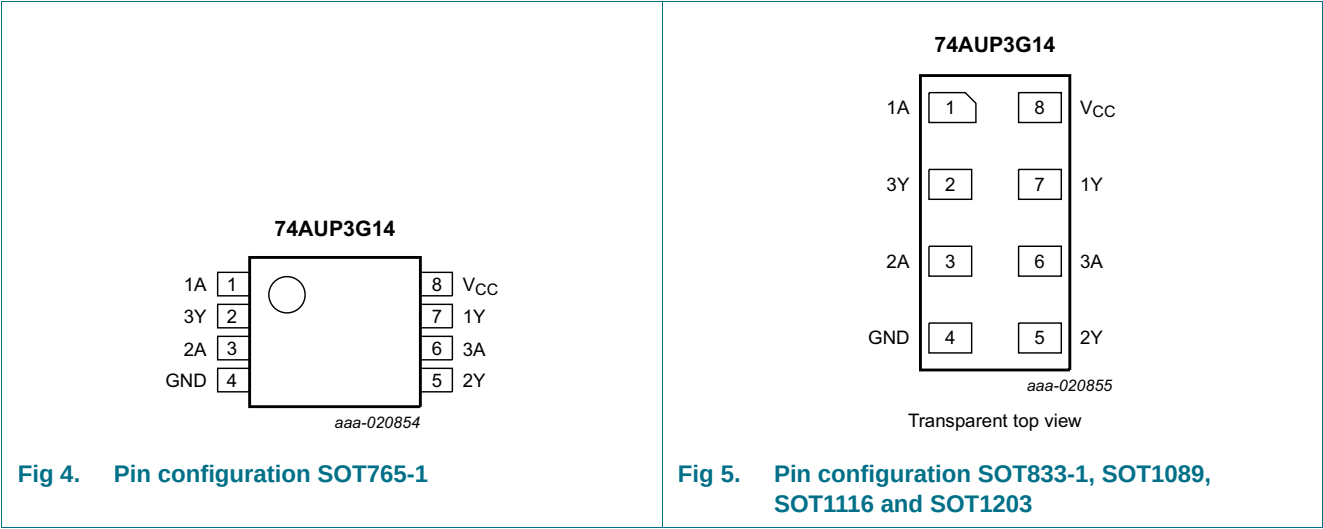
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

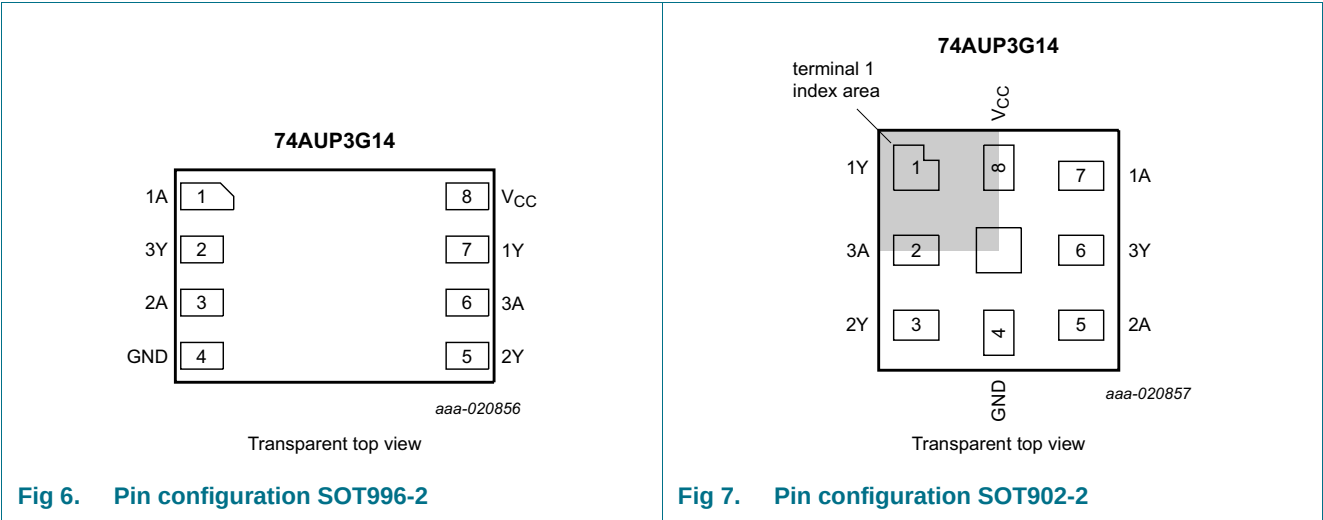
6. Functional diagram



7. Pinning information

7.1 Pinning





7.2 Pin description

Table 3. Pin description

| Symbol          | Pin                                                                  |          | Description    |
|-----------------|----------------------------------------------------------------------|----------|----------------|
|                 | SOT505-2, SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203 | SOT902-2 |                |
| 1A, 2A, 3A      | 1, 3, 6                                                              | 7, 5, 2  | data input     |
| 1Y, 2Y, 3Y      | 7, 5, 2                                                              | 1, 3, 6  | data output    |
| GND             | 4                                                                    | 4        | ground (0 V)   |
| V <sub>CC</sub> | 8                                                                    | 8        | supply voltage |

8. Functional description

Table 4. Function table<sup>[1]</sup>

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | H      |
| H     | L      |

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                          | Min  | Max      | Unit |
|-----------|-------------------------|-------------------------------------|------|----------|------|
| $V_{CC}$  | supply voltage          |                                     | -0.5 | +4.6     | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                         | -50  | -        | mA   |
| $V_I$     | input voltage           | [1]                                 | -0.5 | +4.6     | V    |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                         | -50  | -        | mA   |
| $V_O$     | output voltage          | Active mode and Power-down mode [1] | -0.5 | +4.6     | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$             | -    | $\pm 20$ | mA   |
| $I_{CC}$  | supply current          |                                     | -    | 50       | mA   |
| $I_{GND}$ | ground current          |                                     | -50  | -        | mA   |
| $T_{stg}$ | storage temperature     |                                     | -65  | +150     | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C [2]   | -    | 250      | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of  $P_{tot}$  derates linearly with 2.5 mW/K.

For VSSOP8 package: above 110 °C the value of  $P_{tot}$  derates linearly with 8 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol    | Parameter           | Conditions                      | Min | Max      | Unit |
|-----------|---------------------|---------------------------------|-----|----------|------|
| $V_{CC}$  | supply voltage      |                                 | 0.8 | 3.6      | V    |
| $V_I$     | input voltage       |                                 | 0   | 3.6      | V    |
| $V_O$     | output voltage      | Active mode                     | 0   | $V_{CC}$ | V    |
|           |                     | Power-down mode; $V_{CC} = 0$ V | 0   | 3.6      | V    |
| $T_{amb}$ | ambient temperature |                                 | -40 | +125     | °C   |

## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                    | Parameter                            | Conditions                                                                                          | Min                    | Typ | Max                   | Unit |
|-------------------------------------------|--------------------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|-----------------------|------|
| <b>T<sub>amb</sub> = 25 °C</b>            |                                      |                                                                                                     |                        |     |                       |      |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                 |                        |     |                       |      |
|                                           |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.75 × V <sub>CC</sub> | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 1.11                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.32                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 2.05                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.9                    | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.72                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.6                    | -   | -                     | V    |
| V <sub>OL</sub>                           | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                 |                        |     |                       |      |
|                                           |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.1                   | V    |
|                                           |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.3 × V <sub>CC</sub> | V    |
|                                           |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.44                  | V    |
|                                           |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.44                  | V    |
| I <sub>I</sub>                            | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.1                  | µA   |
| I <sub>OFF</sub>                          | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.2                  | µA   |
| ΔI <sub>OFF</sub>                         | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.2                  | µA   |
| I <sub>CC</sub>                           | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.5                   | µA   |
| ΔI <sub>CC</sub>                          | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | -                      | -   | 40                    | µA   |
| C <sub>I</sub>                            | input capacitance                    | V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 0 V to 3.6 V                            | -                      | 1.1 | -                     | pF   |
| C <sub>O</sub>                            | output capacitance                   | V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V                                                         | -                      | 1.7 | -                     | pF   |
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> |                                      |                                                                                                     |                        |     |                       |      |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                 |                        |     |                       |      |
|                                           |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.7 × V <sub>CC</sub>  | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 1.03                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.30                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.97                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.85                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.67                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.55                   | -   | -                     | V    |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                            | Conditions                                                                                          | Min                    | Typ | Max                    | Unit |
|--------------------------------------------|--------------------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                 |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.1                    | V    |
|                                            |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                            |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.37                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.35                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.33                   | V    |
|                                            |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.45                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.33                   | V    |
|                                            |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.45                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.5                   | µA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.5                   | µA   |
| ΔI <sub>OFF</sub>                          | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.6                   | µA   |
| I <sub>CC</sub>                            | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.9                    | µA   |
| ΔI <sub>CC</sub>                           | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | -                      | -   | 50                     | µA   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                      |                                                                                                     |                        |     |                        |      |
| V <sub>OH</sub>                            | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                 |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 0.93                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.17                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.77                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.67                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.40                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                 |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.11                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|                                            |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.41                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.39                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.36                   | V    |
|                                            |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.50                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.36                   | V    |
|                                            |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.50                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.75                  | µA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.75                  | µA   |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                            | Conditions                                                                 | Min | Typ | Max        | Unit    |
|------------------|--------------------------------------|----------------------------------------------------------------------------|-----|-----|------------|---------|
| $\Delta I_{OFF}$ | additional power-off leakage current | $V_I$ or $V_O = 0$ V to 3.6 V;<br>$V_{CC} = 0$ V to 0.2 V                  | -   | -   | $\pm 0.75$ | $\mu$ A |
| $I_{CC}$         | supply current                       | $V_I = \text{GND}$ or $V_{CC}$ ; $I_O = 0$ A;<br>$V_{CC} = 0.8$ V to 3.6 V | -   | -   | 1.4        | $\mu$ A |
| $\Delta I_{CC}$  | additional supply current            | $V_I = V_{CC} - 0.6$ V; $I_O = 0$ A;<br>$V_{CC} = 3.3$ V                   | -   | -   | 75         | $\mu$ A |

## 12. Dynamic characteristics

**Table 8.** Dynamic characteristicsVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol                 | Parameter         | Conditions                                            | 25 °C |                    |      | −40 °C to +125 °C |             |              | Unit |
|------------------------|-------------------|-------------------------------------------------------|-------|--------------------|------|-------------------|-------------|--------------|------|
|                        |                   |                                                       | Min   | Typ <sup>[1]</sup> | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| C <sub>L</sub> = 5 pF  |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 19.9               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 2.7   | 5.9                | 11.0 | 2.4               | 11.1        | 11.2         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 2.6   | 4.3                | 6.6  | 2.4               | 7.1         | 7.4          | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 2.1   | 3.7                | 5.4  | 2.0               | 6.0         | 6.2          | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 2.0   | 3.0                | 4.1  | 1.7               | 4.5         | 4.7          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 1.9   | 2.8                | 3.6  | 1.5               | 3.9         | 4.0          | ns   |
| C <sub>L</sub> = 10 pF |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 23.4               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 2.9   | 6.8                | 12.7 | 2.8               | 12.8        | 12.9         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 2.8   | 5.0                | 7.7  | 2.6               | 8.2         | 8.6          | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 2.7   | 4.2                | 6.2  | 2.5               | 6.7         | 7.1          | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 2.3   | 3.6                | 4.8  | 2.1               | 5.2         | 5.5          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 2.1   | 3.3                | 4.3  | 2.0               | 4.5         | 4.7          | ns   |
| C <sub>L</sub> = 15 pF |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 26.9               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 3.3   | 7.6                | 14.3 | 3.0               | 14.5        | 14.7         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 3.3   | 5.5                | 8.6  | 2.9               | 9.4         | 9.8          | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 2.8   | 4.7                | 7.0  | 2.8               | 7.7         | 8.1          | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 2.7   | 4.0                | 5.5  | 2.4               | 5.9         | 6.2          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 2.6   | 3.8                | 4.8  | 2.2               | 5.2         | 5.4          | ns   |

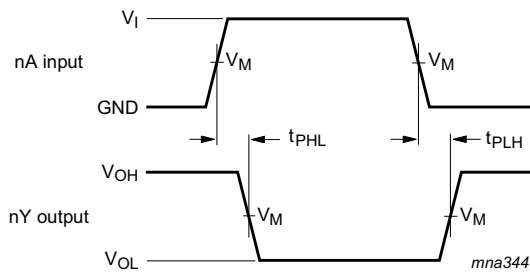


**Table 8. Dynamic characteristics ...continued**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol                                        | Parameter                     | Conditions                                                                        | 25 °C |                    |      | −40 °C to +125 °C |             |              | Unit |
|-----------------------------------------------|-------------------------------|-----------------------------------------------------------------------------------|-------|--------------------|------|-------------------|-------------|--------------|------|
|                                               |                               |                                                                                   | Min   | Typ <sup>[1]</sup> | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| C <sub>L</sub> = 30 pF                        |                               |                                                                                   |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>                               | propagation delay             | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup>                             |       |                    |      |                   |             |              |      |
|                                               |                               | V <sub>CC</sub> = 0.8 V                                                           | -     | 37.3               | -    | -                 | -           | -            | ns   |
|                                               |                               | V <sub>CC</sub> = 1.1 V to 1.3 V                                                  | 4.0   | 9.8                | 18.7 | 3.9               | 19.6        | 20.0         | ns   |
|                                               |                               | V <sub>CC</sub> = 1.4 V to 1.6 V                                                  | 3.7   | 7.1                | 11.2 | 3.8               | 12.3        | 12.9         | ns   |
|                                               |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                                | 3.6   | 6.0                | 9.1  | 3.6               | 10.0        | 10.6         | ns   |
|                                               |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                                  | 3.5   | 5.2                | 6.9  | 3.2               | 7.5         | 7.9          | ns   |
|                                               |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                                  | 3.3   | 4.8                | 6.1  | 3.1               | 7.1         | 7.4          | ns   |
| C <sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF |                               |                                                                                   |       |                    |      |                   |             |              |      |
| C <sub>PD</sub>                               | power dissipation capacitance | f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[3][4]</sup> |       |                    |      |                   |             |              |      |
|                                               |                               | V <sub>CC</sub> = 0.8 V                                                           | -     | 2.6                | -    | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.1 V to 1.3 V                                                  | -     | 2.7                | -    | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.4 V to 1.6 V                                                  | -     | 2.9                | -    | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                                | -     | 3.1                | -    | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                                  | -     | 3.7                | -    | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                                  | -     | 4.3                | -    | -                 | -           | -            | pF   |

- [1] All typical values are measured at nominal V<sub>CC</sub>.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- [3] All specified values are the average typical values over all stated loads.
- [4] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

13. Waveforms

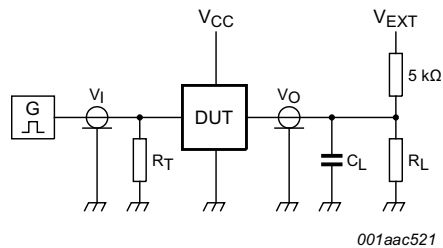


Measurement points are given in [Table 9](#).  
Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig 8. The data input (nA) to output (nY) propagation delays

Table 9. Measurement points

| Supply voltage  | Output                | Input                 |                 |                                 |
|-----------------|-----------------------|-----------------------|-----------------|---------------------------------|
| V <sub>CC</sub> | V <sub>M</sub>        | V <sub>M</sub>        | V <sub>I</sub>  | t <sub>r</sub> = t <sub>f</sub> |
| 0.8 V to 3.6 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | ≤ 3.0 ns                        |



Test data is given in [Table 10](#).  
Definitions for test circuit:  
R<sub>L</sub> = Load resistance.  
C<sub>L</sub> = Load capacitance including jig and probe capacitance.  
R<sub>T</sub> = Termination resistance should be equal to the output impedance Z<sub>o</sub> of the pulse generator.  
V<sub>EXT</sub> = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage  | Load                         |                               | V <sub>EXT</sub>                    |                                     |                                     |
|-----------------|------------------------------|-------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V <sub>CC</sub> | C <sub>L</sub>               | R <sub>L</sub> <sup>[1]</sup> | t <sub>PLH</sub> , t <sub>PHL</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> |
| 0.8 V to 3.6 V  | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ                  | open                                | GND                                 | 2 × V <sub>CC</sub>                 |

[1] For measuring enable and disable times R<sub>L</sub> = 5 kΩ, for measuring propagation delays, set-up and hold times and pulse width R<sub>L</sub> = 1 MΩ.

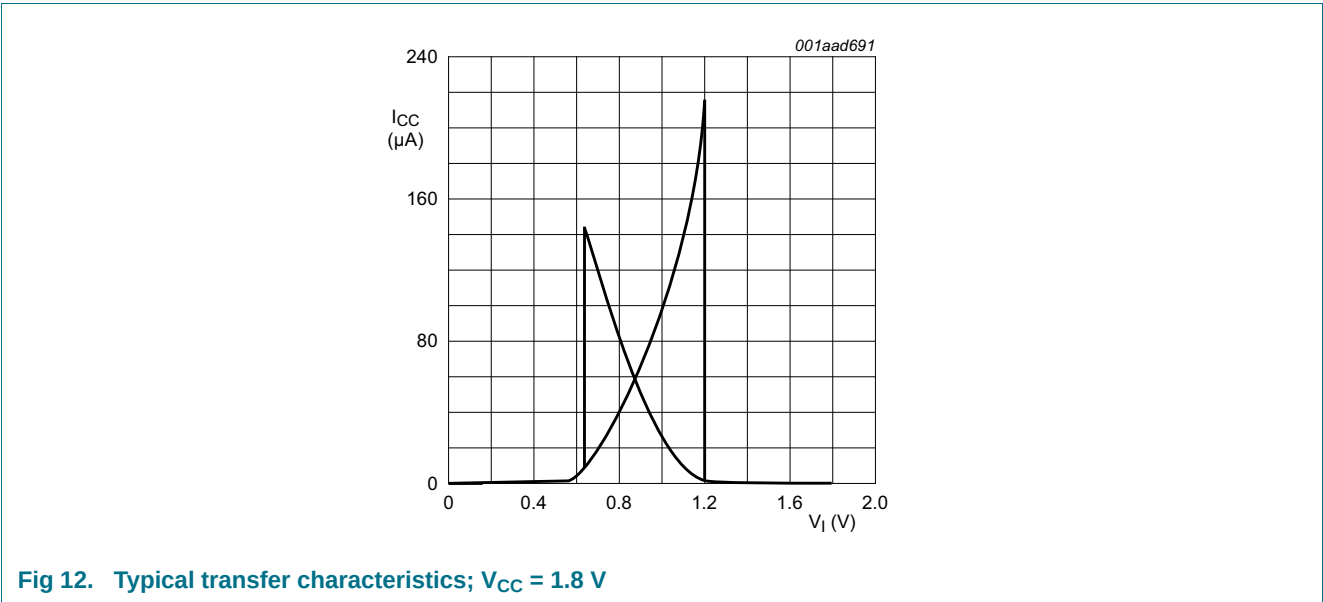
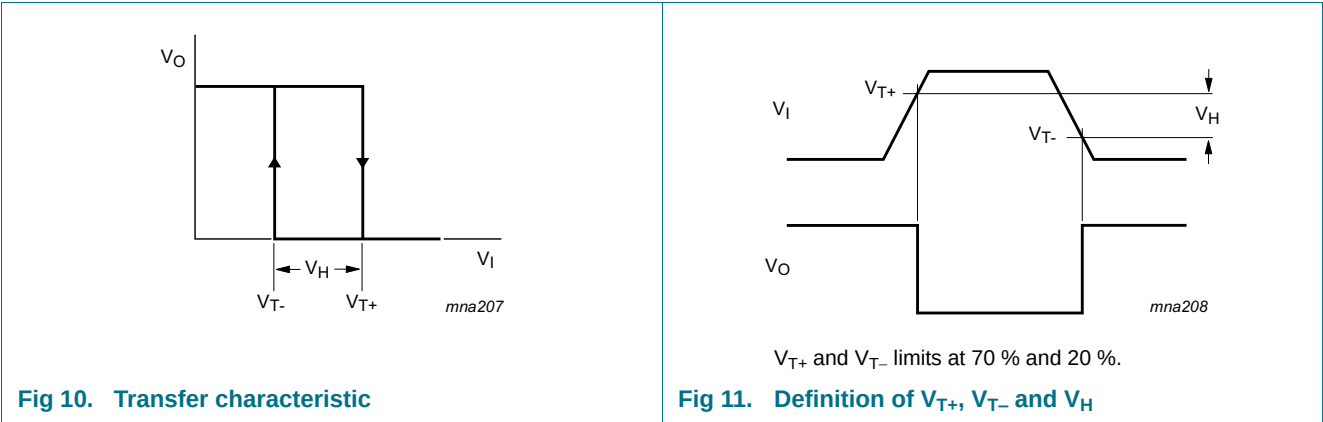
## 14. Transfer characteristics

**Table 11. Transfer characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol          | Parameter                        | Conditions                                                                                                                                                | 25 °C |     |      | –40 °C to +125 °C |             |              | Unit |
|-----------------|----------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-----|------|-------------------|-------------|--------------|------|
|                 |                                  |                                                                                                                                                           | Min   | Typ | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| V <sub>T+</sub> | positive-going threshold voltage | see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>                                                                                               |       |     |      |                   |             |              |      |
|                 |                                  | V <sub>CC</sub> = 0.8 V                                                                                                                                   | 0.30  | -   | 0.60 | 0.30              | 0.60        | 0.62         | V    |
|                 |                                  | V <sub>CC</sub> = 1.1 V                                                                                                                                   | 0.53  | -   | 0.90 | 0.53              | 0.90        | 0.92         | V    |
|                 |                                  | V <sub>CC</sub> = 1.4 V                                                                                                                                   | 0.74  | -   | 1.11 | 0.74              | 1.11        | 1.13         | V    |
|                 |                                  | V <sub>CC</sub> = 1.65 V                                                                                                                                  | 0.91  | -   | 1.29 | 0.91              | 1.29        | 1.31         | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V                                                                                                                                   | 1.37  | -   | 1.77 | 1.37              | 1.77        | 1.80         | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V                                                                                                                                   | 1.88  | -   | 2.29 | 1.88              | 2.29        | 2.32         | V    |
| V <sub>T–</sub> | negative-going threshold voltage | see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>                                                                                               |       |     |      |                   |             |              |      |
|                 |                                  | V <sub>CC</sub> = 0.8 V                                                                                                                                   | 0.10  | -   | 0.60 | 0.10              | 0.60        | 0.60         | V    |
|                 |                                  | V <sub>CC</sub> = 1.1 V                                                                                                                                   | 0.26  | -   | 0.65 | 0.26              | 0.65        | 0.65         | V    |
|                 |                                  | V <sub>CC</sub> = 1.4 V                                                                                                                                   | 0.39  | -   | 0.75 | 0.39              | 0.75        | 0.75         | V    |
|                 |                                  | V <sub>CC</sub> = 1.65 V                                                                                                                                  | 0.47  | -   | 0.84 | 0.47              | 0.84        | 0.84         | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V                                                                                                                                   | 0.69  | -   | 1.04 | 0.69              | 1.04        | 1.04         | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V                                                                                                                                   | 0.88  | -   | 1.24 | 0.88              | 1.24        | 1.24         | V    |
| V <sub>H</sub>  | hysteresis voltage               | (V <sub>T+</sub> – V <sub>T–</sub> ); see <a href="#">Figure 10</a> , <a href="#">Figure 11</a> , <a href="#">Figure 12</a> and <a href="#">Figure 13</a> |       |     |      |                   |             |              |      |
|                 |                                  | V <sub>CC</sub> = 0.8 V                                                                                                                                   | 0.07  | -   | 0.50 | 0.07              | 0.50        | 0.50         | V    |
|                 |                                  | V <sub>CC</sub> = 1.1 V                                                                                                                                   | 0.08  | -   | 0.46 | 0.08              | 0.46        | 0.46         | V    |
|                 |                                  | V <sub>CC</sub> = 1.4 V                                                                                                                                   | 0.18  | -   | 0.56 | 0.18              | 0.56        | 0.56         | V    |
|                 |                                  | V <sub>CC</sub> = 1.65 V                                                                                                                                  | 0.27  | -   | 0.66 | 0.27              | 0.66        | 0.66         | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V                                                                                                                                   | 0.53  | -   | 0.92 | 0.53              | 0.92        | 0.92         | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V                                                                                                                                   | 0.79  | -   | 1.31 | 0.79              | 1.31        | 1.31         | V    |

15. Waveforms transfer characteristics



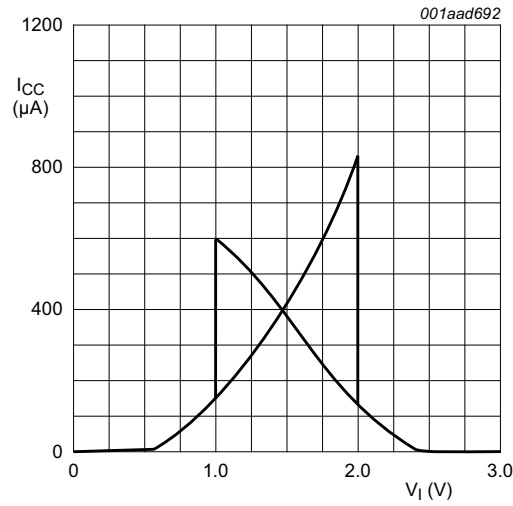


Fig 13. Typical transfer characteristics;  $V_{CC} = 3.0\text{ V}$

## 16. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$P_{\text{add}} = f_i \times (t_r \times \Delta I_{CC(\text{AV})} + t_f \times \Delta I_{CC(\text{AV})}) \times V_{CC} \text{ where:}$$

$P_{\text{add}}$  = additional power dissipation ( $\mu\text{W}$ );

$f_i$  = input frequency (MHz);

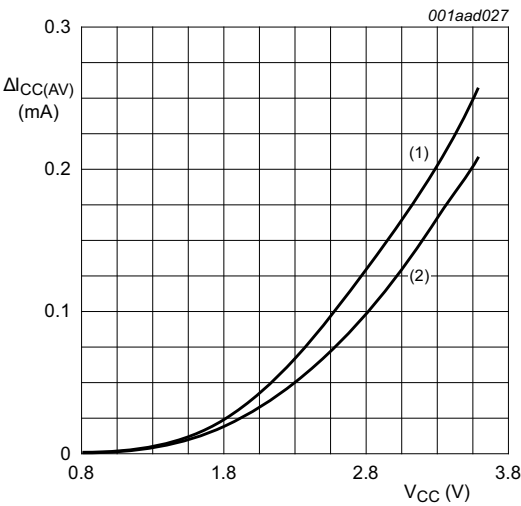
$t_r$  = rise time (ns); 10 % to 90 %;

$t_f$  = fall time (ns); 90 % to 10 %;

$\Delta I_{CC(\text{AV})}$  = average additional supply current ( $\mu\text{A}$ ).

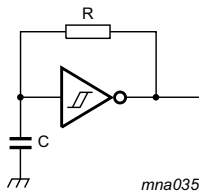
Average  $\Delta I_{CC(\text{AV})}$  differs with positive or negative input transitions, as shown in [Figure 14](#).

An example of a relaxation circuit using the 74AUP3G14 is shown in [Figure 15](#).



- (1) Positive-going edge.
- (2) Negative-going edge.

Fig 14. Average  $I_{CC}$  as a function of  $V_{CC}$



$$f = \frac{1}{T} \approx \frac{1}{a \times RC}$$

Average values for variable a are given in [Table 12](#).

Fig 15. Relaxation oscillator

Table 12. Variable values

| Supply voltage | Variable a |
|----------------|------------|
| 1.1 V          | 1.28       |
| 1.5 V          | 1.22       |
| 1.8 V          | 1.24       |
| 2.8 V          | 1.34       |
| 3.3 V          | 1.45       |

17. Package outline

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

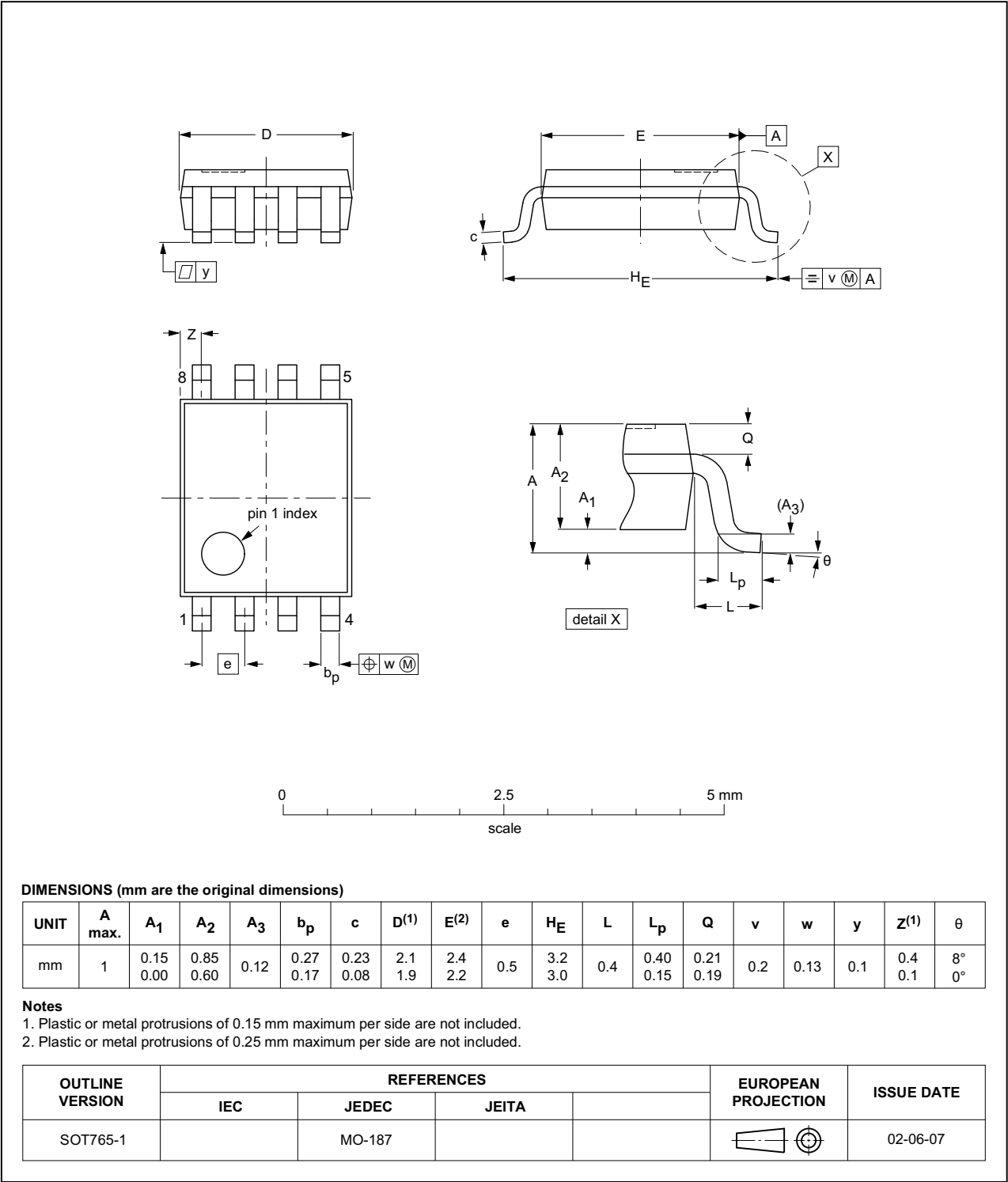


Fig 16. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

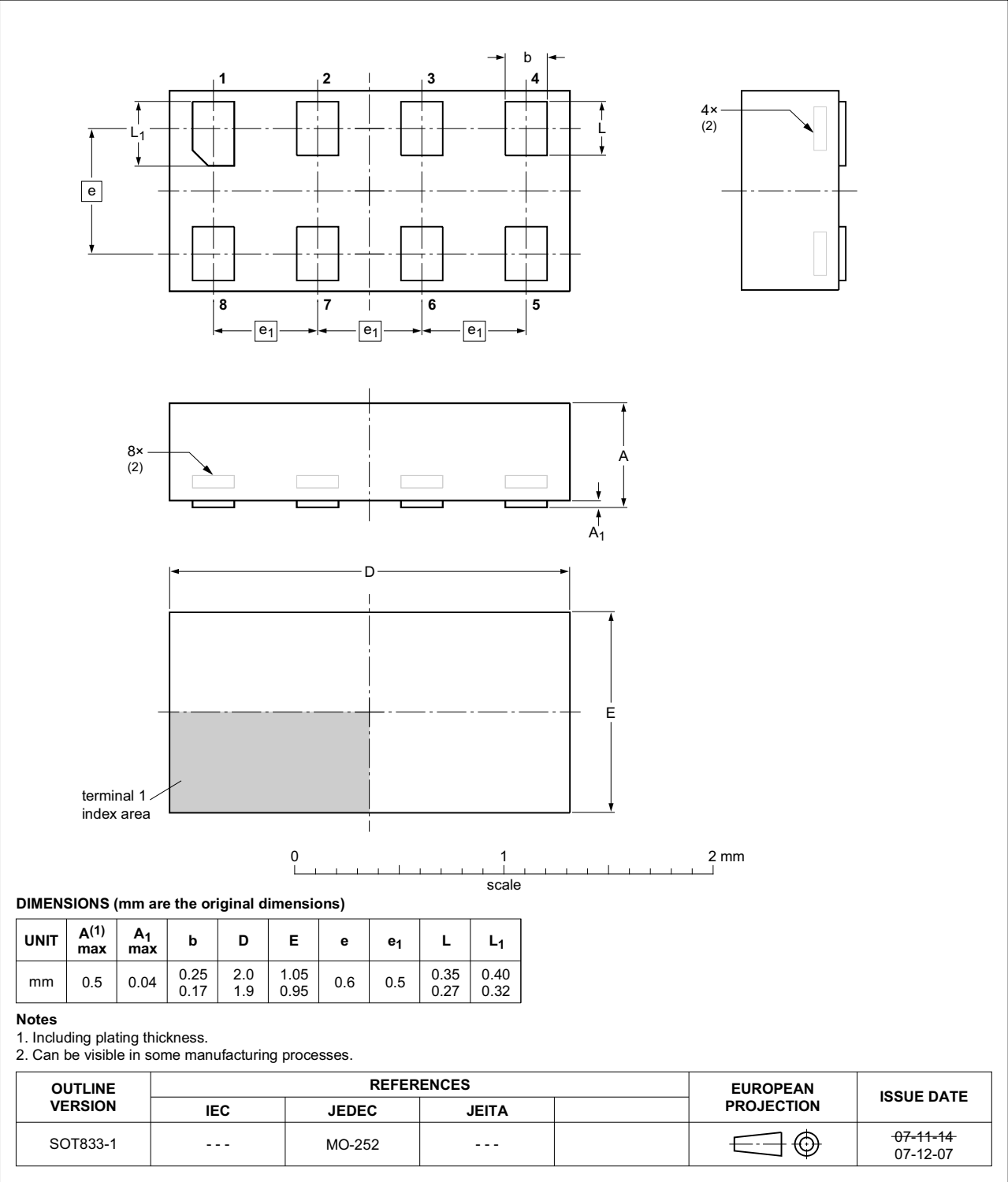


Fig 17. Package outline SOT833-1 (XSON8)



XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.35 x 1 x 0.5 mm

SOT1089

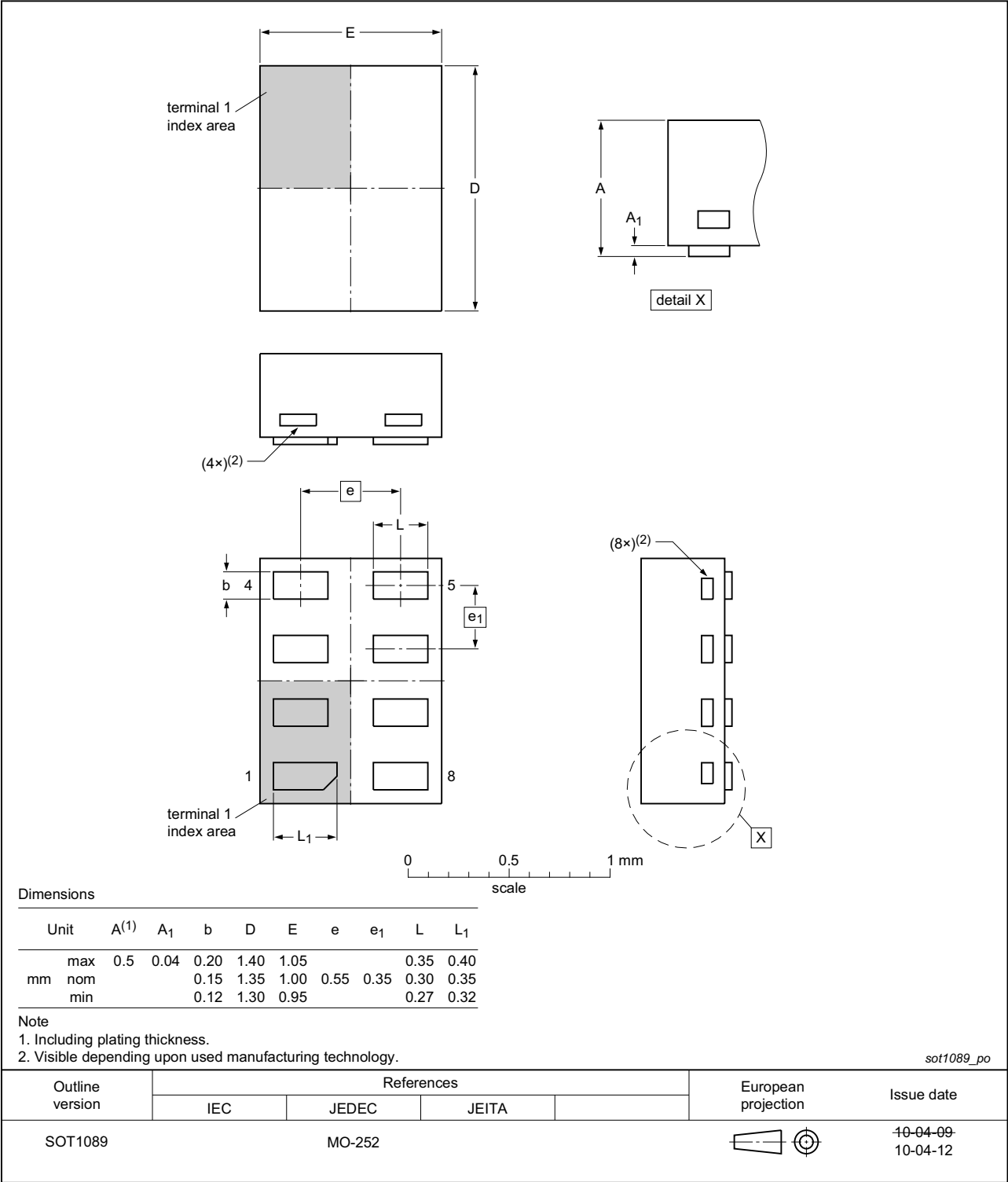


Fig 18. Package outline SOT1089 (XSON8)

XSON8: plastic extremely thin small outline package; no leads;  
8 terminals; body 3 x 2 x 0.5 mm

SOT996-2

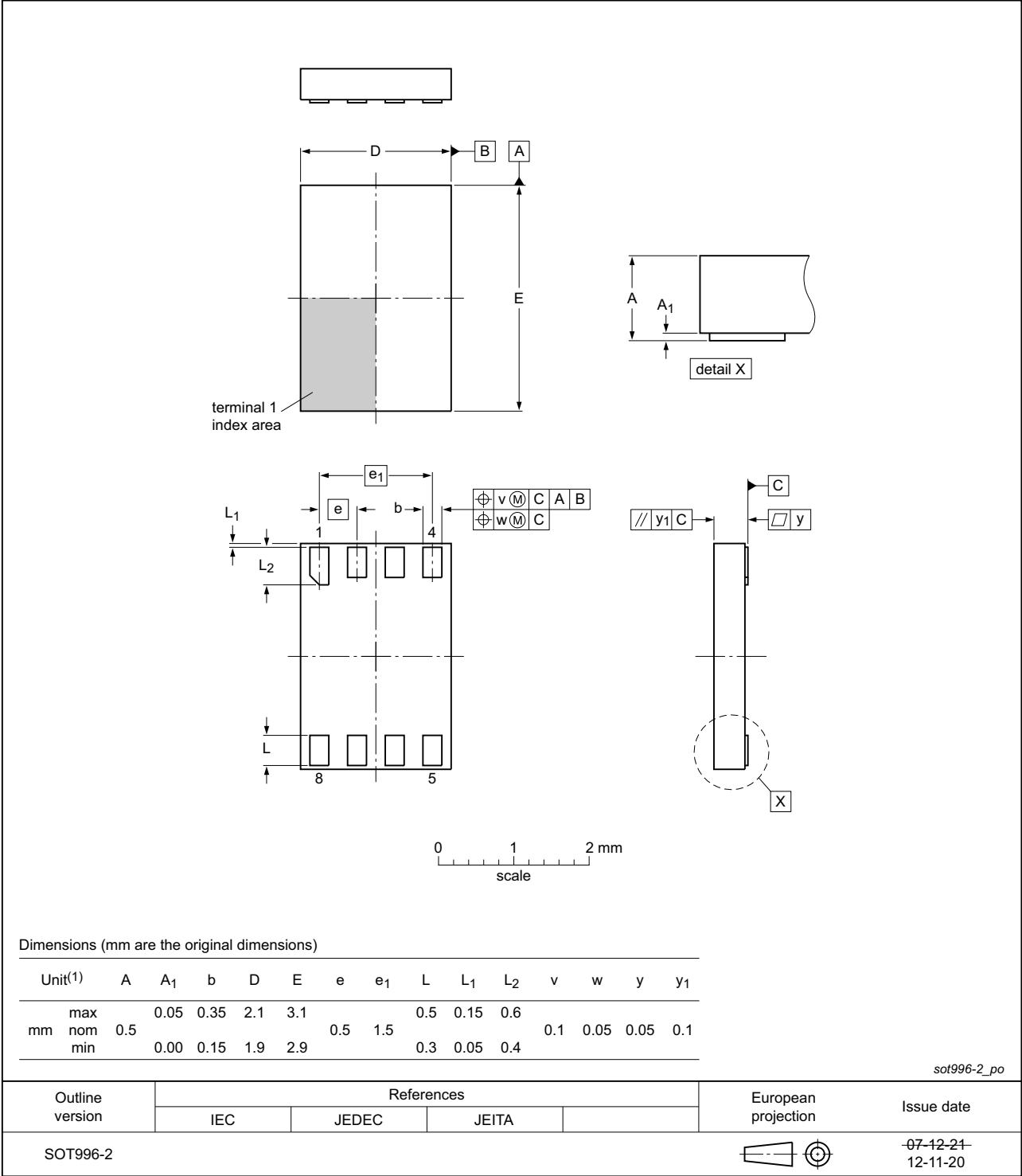


Fig 19. Package outline SOT996-2 (XSON8)

XQFN8: plastic, extremely thin quad flat package; no leads;  
8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-2

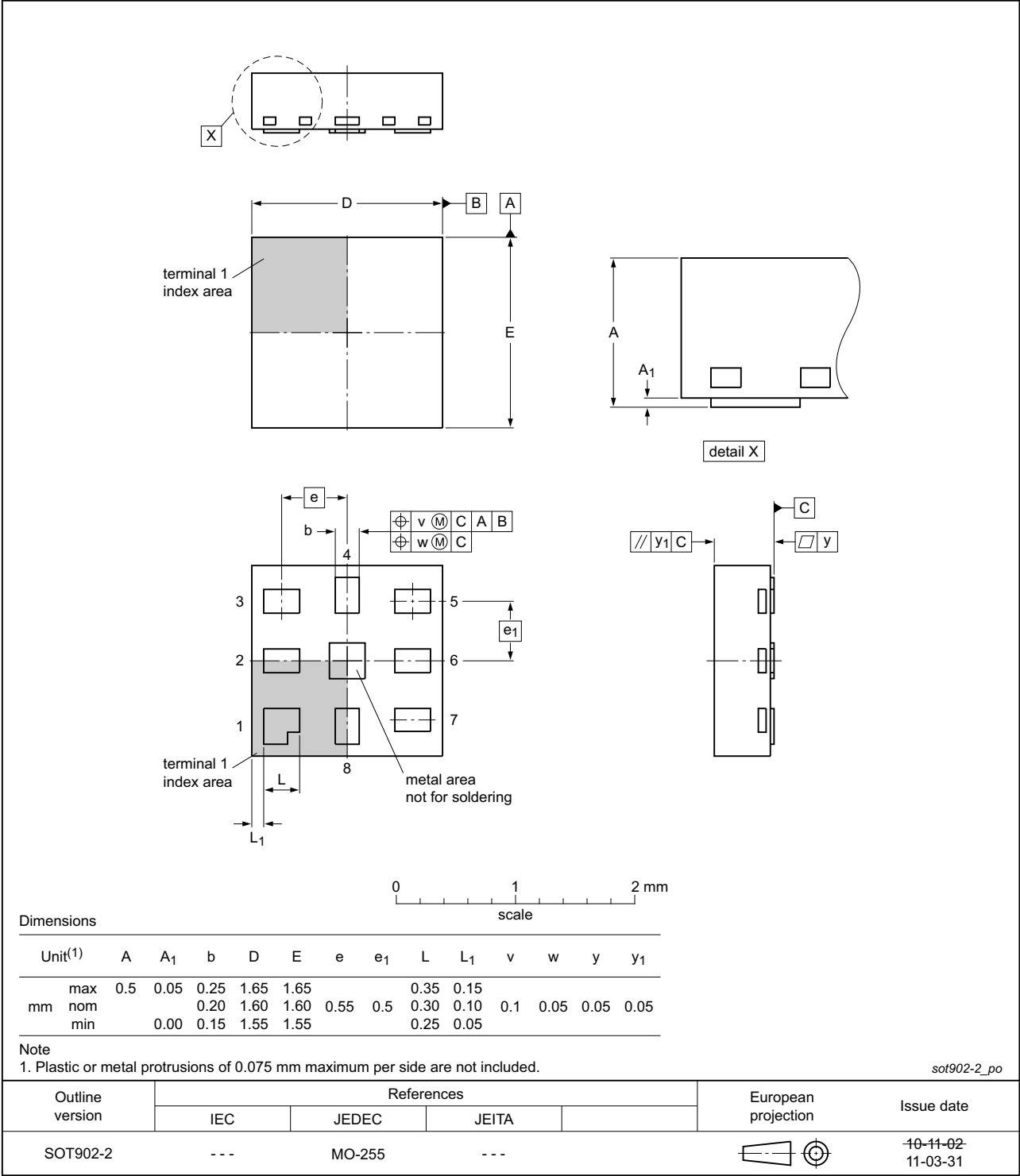


Fig 20. Package outline SOT902-2 (XQFN8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.2 x 1.0 x 0.35 mm

SOT1116

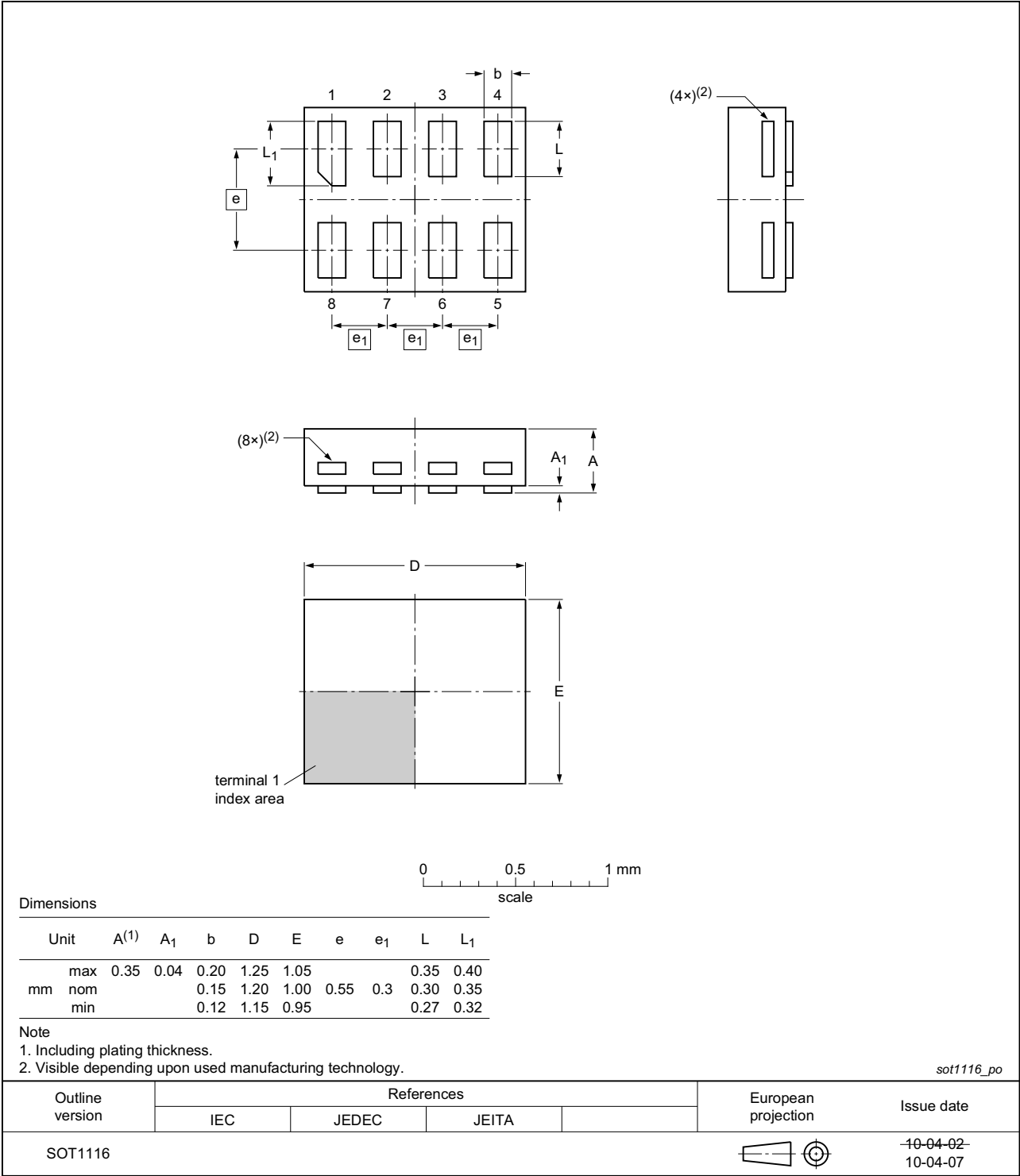


Fig 21. Package outline SOT1116 (XSON8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.35 x 1.0 x 0.35 mm

SOT1203

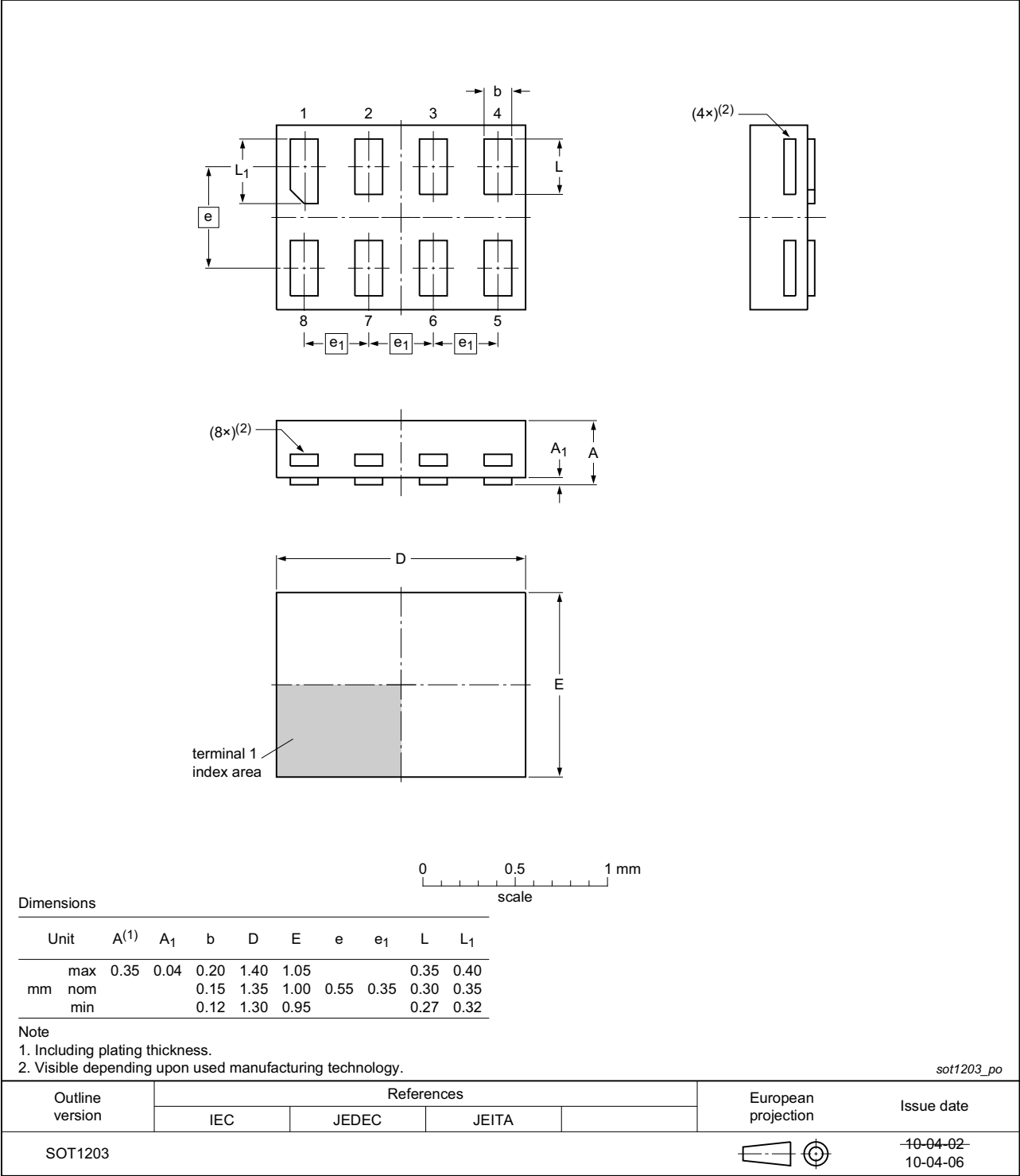


Fig 22. Package outline SOT1203 (XSON8)

## 18. Abbreviations

Table 13. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| HBM     | Human Body Model        |
| MM      | Machine Model           |

## 19. Revision history

Table 14. Revision history

| Document ID   | Release date | Data sheet status  | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| 74AUP3G14 v.1 | 20151222     | Product data sheet | -             | -          |

## 20. Legal information

### 20.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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